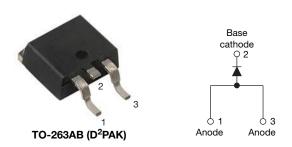
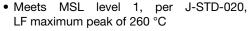


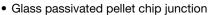
## High Voltage Surface Mount Input Rectifier Diode, 25 A

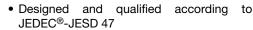


PRODUCT SUMMARY						
Package	TO-263AB (D <sup>2</sup> PAK)					
I <sub>F(AV)</sub>	25 A					
$V_{R}$	800 V, 1000 V, 1200 V					
V <sub>F</sub> at I <sub>F</sub>	1.14 V					
I <sub>FSM</sub>	300 A					
T <sub>j</sub> max.	150 °C					
Diode variation	Single die					

#### **FEATURES**













ROHS COMPLIANT HALOGEN FREE

#### **APPLICATIONS**

- Input rectification
- Vishay switches and output rectifiers which are available in identical package outlines

#### **DESCRIPTION**

The VS-25ETS..SPbF rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS							
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS							
Capacitive input filter T <sub>A</sub> = 55 °C, T <sub>J</sub> = 125 °C common heatsink of 1 °C/W	20	23	А				

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Sinusoidal waveform	25	A						
V <sub>RRM</sub>		800 to 1200	V						
I <sub>FSM</sub>		300	A						
V <sub>F</sub>	10 A, T <sub>J</sub> = 25 °C	1.0	V						
T <sub>J</sub>		-40 to +150	°C						

VOLTAGE RATINGS									
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA						
VS-25ETS08SPbF	800	900							
VS-25ETS10SPbF	1000	1100	1						
VS-25ETS12SPbF	1200	1300							





ABSOLUTE MAXIMUM RATINGS							
PARAMETER	VALUES	UNITS					
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 106 °C, 180° conduction half sine wave	25				
Maximum peak one cycle	I <sub>FSM</sub>	10 ms sine pulse, rated V <sub>RRM</sub> applied	250	Α			
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	300				
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	316	A <sup>2</sup> s			
Maximum I-t for fusing	I-r	10 ms sine pulse, no voltage reapplied	442	A-s			
Maximum I <sup>2</sup> √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s			

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
Maximum forward voltage drop	$V_{FM}$	25 A, T <sub>J</sub> = 25 °C	1.14	V			
Forward slope resistance	r <sub>t</sub>	T <sub>.1</sub> = 150 °C	9.62	mΩ			
Threshold voltage	V <sub>F(TO)</sub>	1J = 130 C	0.87	V			
Maximum reverse leakage current		T <sub>J</sub> = 25 °C		0.1	mA		
Maximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 150 °C	V <sub>R</sub> = Rated V <sub>RRM</sub>	1.0	IIIA		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and stemperature range	storage	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C		
Maximum thermal resist junction to case	ance,	R <sub>thJC</sub>	DC operation	0.9			
Maximum thermal resist junction to ambient	ance,	R <sub>thJA</sub>		62	°C/W		
Typical thermal resistant case to heatsink	Typical thermal resistance, case to heatsink		Mounting surface, smooth and greased	0.5			
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Mounting toward	minimum			6 (5)	kgf · cm		
Mounting torque	Mounting torque maximum			12 (10)	(lbf ⋅ in)		
Marking device				25ETS08S			
			Case style TO-263AB (D <sup>2</sup> PAK)	25ETS10S			
	-			25ETS12S			

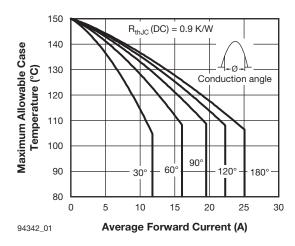


Fig. 1 - Current Rating Characteristics

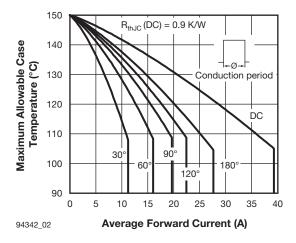


Fig. 2 - Current Rating Characteristics

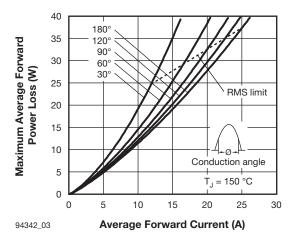


Fig. 3 - Forward Power Loss Characteristics

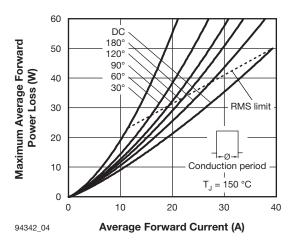


Fig. 4 - Forward Power Loss Characteristics

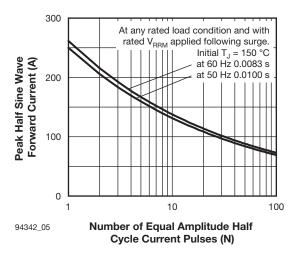


Fig. 5 - Maximum Non-Repetitive Surge Current

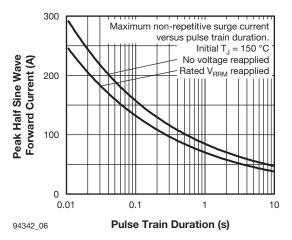


Fig. 6 - Maximum Non-Repetitive Surge Current

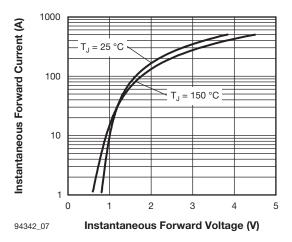


Fig. 7 - Forward Voltage Drop Characteristics

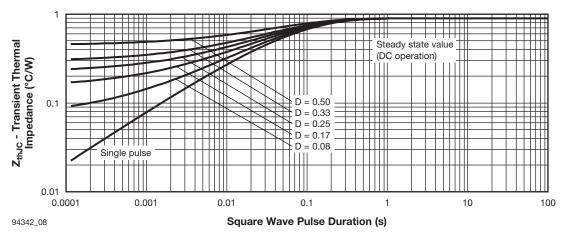
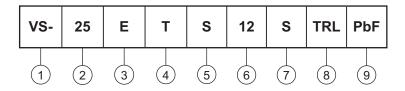


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

Current rating (25 = 25 A)

Circuit configuration

E = single diode

- Package:

T = TO-220AC

5 - Type of silicon:

S = standard recovery rectifier

V = 800 V

6 - Voltage code x 100 = V<sub>RRM</sub>

10 = 1000 V

7 - S = TO-220 D<sup>2</sup>PAK (SMD-220) version

12 = 1200 V

8 - None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

9 - PbF = lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-25ETS08SPbF	50	1000	Antistatic plastic tube					
VS-25ETS08STRRPbF	800	800	13" diameter reel					
VS-25ETS08STRLPbF	800	800	13" diameter reel					
VS-25ETS10SPbF	50	1000	Antistatic plastic tube					
VS-25ETS10STRRPbF	800	800	13" diameter reel					
VS-25ETS10STRLPbF	800	800	13" diameter reel					
VS-25ETS12SPbF	50	1000	Antistatic plastic tube					
VS-25ETS12STRRPbF	800	800	13" diameter reel					
VS-25ETS12STRLPbF	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95046				
Part marking information	www.vishay.com/doc?95054				
Packaging information	www.vishay.com/doc?95032				



### D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

### **Legal Disclaimer Notice**



Vishay

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